

Solid State Relay OCMOS FET

PS7122-1A,-2A,PS7122L-1A,-2A

6, 8-PIN DIP, 200 V BREAK DOWN VOLTAGE 1-ch, 2-ch Optical Coupled MOS FET

DESCRIPTION

The PS7122-1A, -2A and PS7122L-1A, -2A are solid state relays containing GaAs LEDs on the light emitting side (input side) and MOS FETs on the output side.

They are suitable for analog signal control because of their low offset and high linearity.

The PS7122L-1A, -2A have a surface mount type lead.

* FEATURES

- 1 channel type (1 a output) or 2 channel type (1 a + 1 a output)
- Low LED operating current (IF = 2 mA)
- · Designed for AC/DC switching line changer
- Small package (6, 8-pin DIP)
- · Low offset voltage
- PS7122L-1A, -2A: Surface mount type
- UL approved: File No. E72422 (S)
- BSI approved: No. 8245/8246
- · CSA approved: No. CA 101391

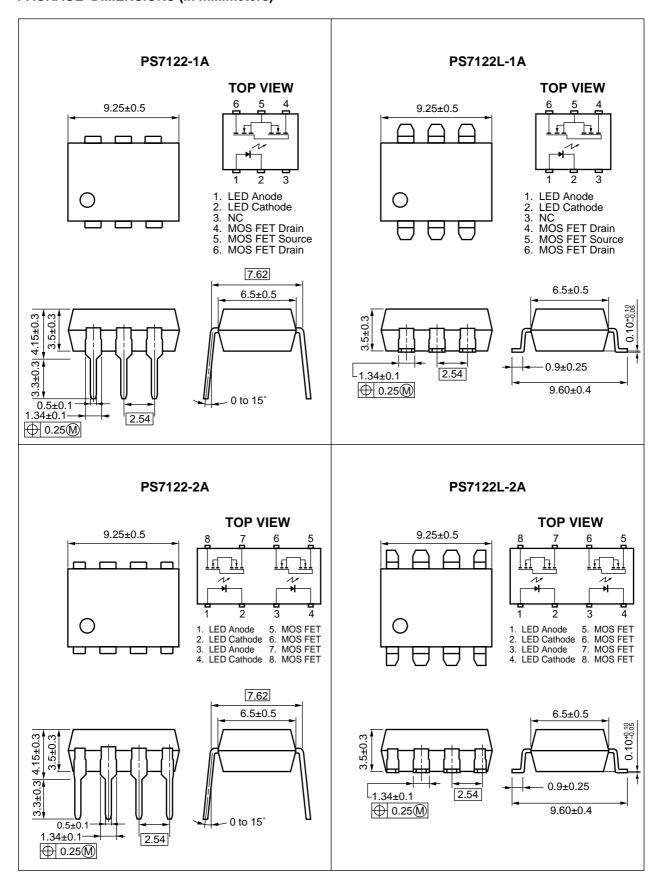
APPLICATIONS

- · Exchange equipment
- · Measurement equipment
- FA/OA equipment

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

PACKAGE DIMENSIONS (in millimeters)



★ ORDERING INFORMATION

| Part Number | Package | Packing Style | Application Part Number*1 |
|---------------|-----------|------------------------------|---------------------------|
| PS7122-1A | 6-pin DIP | Magazine case 50 pcs | PS7122-1A |
| PS7122L-1A | | | PS7122L-1A |
| PS7122L-1A-E3 | | Embossed Tape 1 000 pcs/reel | |
| PS7122L-1A-E4 | | | |
| PS7122-2A | 8-pin DIP | Magazine case 50 pcs | PS7122-2A |
| PS7122L-2A | | | PS7122L-2A |
| PS7122L-2A-E3 | | Embossed Tape 1 000 pcs/reel | |
| PS7122L-2A-E4 | | | |

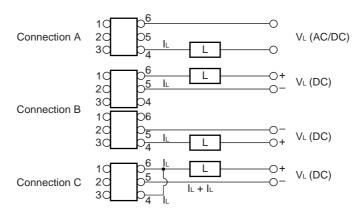
^{*1} For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

| Parameter | | | | Rati | | |
|-------------------------------|--|--------------|------------------|--------------------------|--------------------------|---------|
| | | | Symbol | PS7122-1A, PS7122L-1A | PS7122-2A, PS7122L-2A | Unit |
| Diode | Diode Forward Current (DC) Reverse Voltage Power Dissipation | | I F | 50 | | mA |
| | | | VR | 5.0 | | V |
| | | | Po | 50 | | mW/ch |
| | Peak Forward Current ^{*1} | | IFP | 1 | | Α |
| MOS FET | FET Break Down Voltage | | VL | 200 | | V |
| | Continuous | Connection A | l _L | 200 | | mA |
| | Load Current ^{*2} | Connection B | | 350 | - | |
| | | Connection C | | 500 | - | |
| | Pulse Load Current ^{*3} (AC/DC Connection) | | ILP | 400 | | mA |
| | Power Dissipation | | Po | 560 | 375 | mW/ch |
| Isolation Voltage '4 | | | BV | 1 500 | | Vr.m.s. |
| Total Power Dissipation | | | Рт | 610 | 850 | mW |
| Operating Ambient Temperature | | | TA | -40 to +80 | | °C |
| Storage Temperature | | | T _{stg} | -40 to +100 | | °C |

^{*1} PW = 100 μ s, Duty Cycle = 1 %

^{*2} Conditions: IF \geq 2 mA. The following types of load connections are available.



^{*3} PW = 100 ms, 1 shot

^{*4} AC voltage for 1 minute at $T_A = 25$ °C, RH = 60 % between input and output

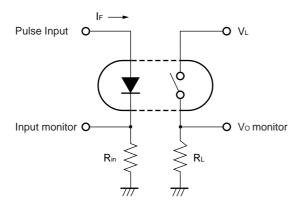
RECOMMENDED OPERATING CONDITIONS (TA = 25 °C)

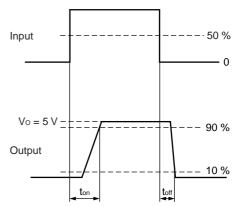
| Parameter | Symbol | MIN. | TYP. | MAX. | Unit |
|-----------------------|--------|------|------|------|------|
| LED Operating Current | lF | 2 | 10 | 20 | mA |
| LED Off Voltage | VF | 0 | | 0.5 | V |

★ ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

| Parameter | | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-----------|--|------------------|--|------|------|------|-------|
| Diode | Forward Voltage | | IF = 10 mA | | 1.2 | 1.4 | V |
| | Reverse Current | lR | V _R = 5 V | | | 5.0 | μΑ |
| MOS FET | Off-state Leakage Current I _{Loff} V _D = 200 V | | | 0.03 | 1.0 | μΑ | |
| | Output Capacitance | Cout | V _D = 0 V, f = 1 MHz | | 165 | | pF/ch |
| Coupled | LED On-state Current | I Fon | IL = 200 mA | | | 2.0 | mA |
| | On-state Resistance | Ron1 | IF = 10 mA, IL = 10 mA | | 3.0 | 5.0 | Ω |
| | | Ron2 | $I_F = 10 \text{ mA}, I_L = 200 \text{ mA}, t \le 10 \text{ ms}$ | | | | |
| | Turn-on Time ^{*1} | ton | I _F = 10 mA, V _O = 5 V, PW ≥ 10 ms | | 0.6 | 2.0 | ms |
| | Turn-off Time ^{*1} | toff | | | 0.06 | 0.2 | |
| | Isolation Resistance | R _{I-O} | Vi-o = 1.0 kVpc | 10° | | | Ω |
| | Isolation Capacitance | C _{I-O} | V = 0 V, f = 1 MHz | | 1.1 | | pF/ch |

*1 Test Circuit for Switching Time



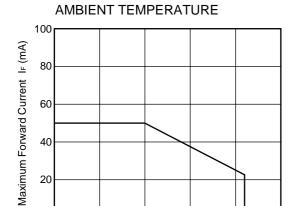


0

-25

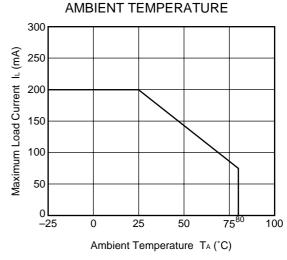
MAXIMUM LOAD CURRENT vs.

TYPICAL CHARACTERISTICS (TA = 25 °C, unless otherwise specified)

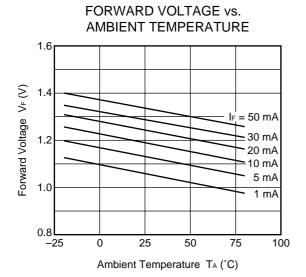


MAXIMUM FORWARD CURRENT vs.

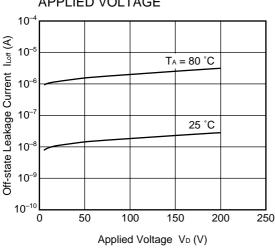
Ambient Temperature TA (°C)



OUTPUT CAPACITANCE vs.



OFF-STATE LEAKAGE CURRENT vs. APPLIED VOLTAGE



APPLIED VOLTAGE 250 f = 1 MHzOutput Capacitance Cout (pF)

60 Applied Voltage V_D (V)

80

100

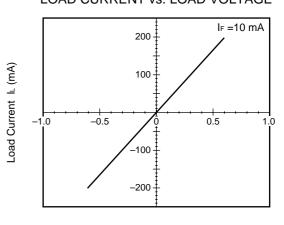
120

20

40

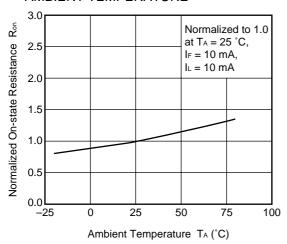
0

LOAD CURRENT vs. LOAD VOLTAGE

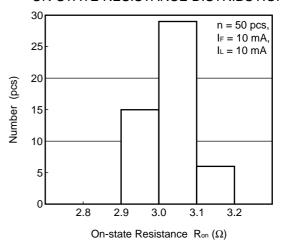


Load Voltage V_L (V)

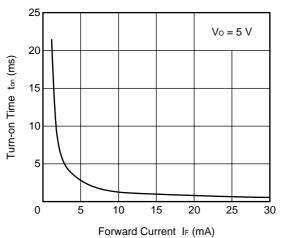
NORMALIZED ON-STATE RESISTANCE vs. AMBIENT TEMPERATURE



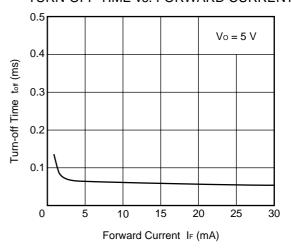
ON-STATE RESISTANCE DISTRIBUTION



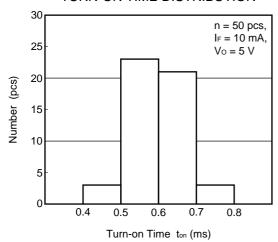
TURN-ON TIME vs. FORWARD CURRENT



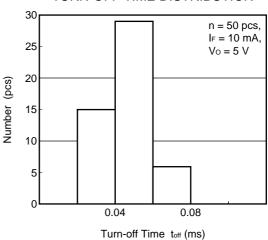
TURN-OFF TIME vs. FORWARD CURRENT



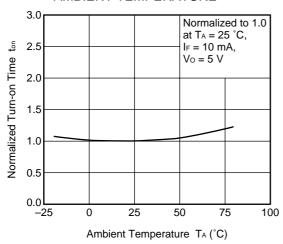
TURN-ON TIME DISTRIBUTION



TURN-OFF TIME DISTRIBUTION

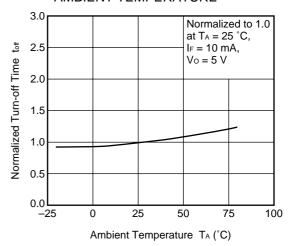


NORMALIZED TURN-ON TIME vs. AMBIENT TEMPERATURE

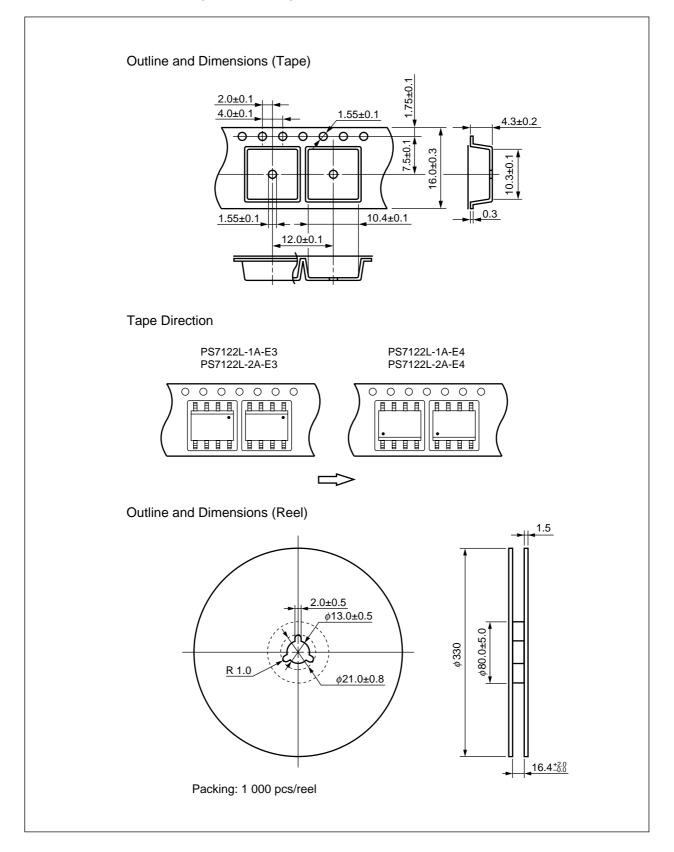


Remark The graphs indicate nominal characteristics.

NORMALIZED TURN-OFF TIME vs. AMBIENT TEMPERATURE



* TAPING SPECIFICATIONS (in millimeters)



RECOMMENDED SOLDERING CONDITIONS

(1) Infrared reflow soldering

• Peak reflow temperature 235 °C (package surface temperature)

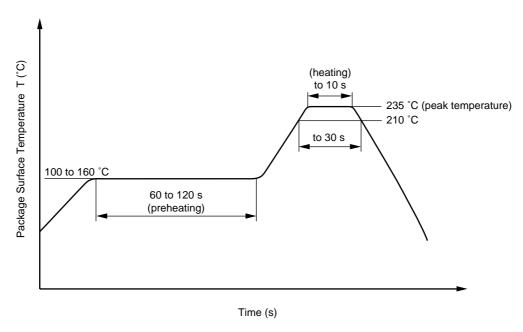
• Time of temperature higher than 210 °C 30 seconds or less

• Number of reflows Two

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt % is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Dip soldering

• Temperature 260 °C or below (molten solder temperature)

• Time 10 seconds or less

• Number of times One

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of

0.2 Wt % is recommended.)

(3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

[MEMO]

CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

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